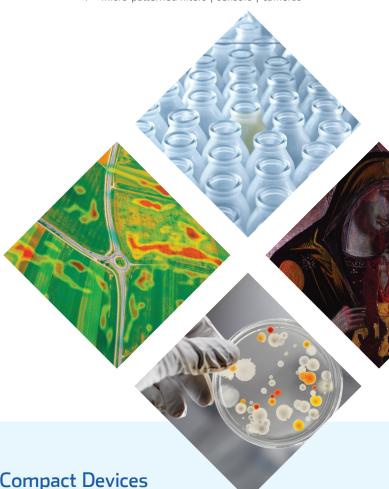
PixelSensor™

Multispectral Sensors







Multispectral Sensors for Compact Devices

PixelSensor™ multispectral sensors use exclusive on-chip filtering to pack up to 8 wavelength-selective photodiodes into a compact 9x9mm array format for simpler and smaller optical devices. One PixelSensor™ replaces multiple components, helping OEMs shrink multi-wavelength instruments for applications including *in vitro* diagnostics, biochemical assays and colorimetry applications.

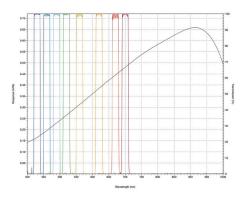
The unique, wafer-level optical filters split the spectrum into 8 discrete color bands and suppress out-of-band background light, improving contrast and sensitivity. Customized OEM versions are available with user-defined spectral bands. With narrow band VIS-NIR selectivity, the sensor arrays are available both with and without an OEM electronics board.

The OEM electronics board is designed for easy integration into customers' analytical equipment and provides a smaller footprint (45.72x21.34mm) and faster time-to-market than traditional sensor technology, offering a cost-effective solution. The parallel channel design results in no moving parts and faster measurements than discrete optics designs and spectrometers. Designed for low noise and fast response time, the 20-pin LCC package can be surface or socket mounted.

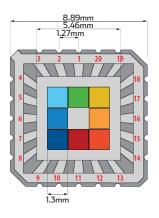
The optional PixelSensor™ OEM electronics board and accessories and simple-to-use software interface provide designers with tools for rapid prototyping and development – to help quickly move your device from concept to scalable production.



Spectral Response | PixelSensor™ 8-band VIS



Photodiode Array Dimensions



Standard & Custom Wavelengths Available

PixelSensor™ Filters				
CWL (nm)	FWHM (nm)			
425*	10			
455*	10			
465	30			
485*	10			
512	26			
515*	15			
555*	15			
558	36			
575	30			
610	30			
615*	15			
660*	20			
661	38			
695*	10			
720	50			
850	30			
Color Gels				
Cyan	Red			
Magenta	Green			

Color Gels		
Cyan	Red	
Magenta	Green	
Yellow	Blue	

*Included in standard configuration

Photodiode Performance Characteristics

Characterisic	Symbol	Test	Min	Typical	Max	Unit
Dark current	I _D	V _R = 10V		2	8	nA
Shunt resistance	R _{sh}	V _R = 10mV		100		MΩ
Junction capacity	C _J	V _R = 0V, f=100kHz V _R = 50V, f=100kHz		6 0.6	7 0.7	pF
Spectral range	^λ range	Spot scan	400		1100	nm
Breakdown voltage	V _{BR}	Ι = 10μΑ		75		V
Noise equivalent power	NEP	V _R = 5V @ λ = peak		5x10 ⁻¹⁴		W/vHz
Response time	t,	$R_L = 50\Omega$, $V_R = 50V$		6.0		ns
Absolute maximum rating						
Reverse voltage	V _{BR}			75		V
Operating temperature	T _o		-40	to	+80	*C

Benefits

- 8-band sensor array in 9x9mm footprint
- Available with or without OEM electronics board (45.72x21.34mm)
- Simplified optics for miniaturized devices
- Narrow band VIS-NIR selectivity (400-1000nm)
- OEM versions available

Customizable Options

- Optical filter specification
- Number of channels
- Package type
- Breakout board & light guide tube accessories

Applications

- Biomedical instrumentation
- Color meters & monitors
- Industrial sorting & sensing
- Portable optical sensors
- OEM multispectral devices

LCC Sensor

Spectral filters	Standard & custom 10 - 100nm FWHM
Photodiodes	Si, 1.0 x 0.8mm
Package	LCC 20

OEM Board Specifications

Integration time	1-1024ms
Gain reference	20-5120nA
Interface	USB 2.0
Protocol	HID-compliant
Software	Windows 32/64bit compatible

OEM Board Dimensions

